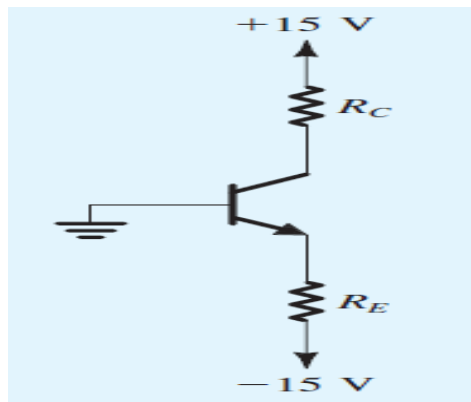
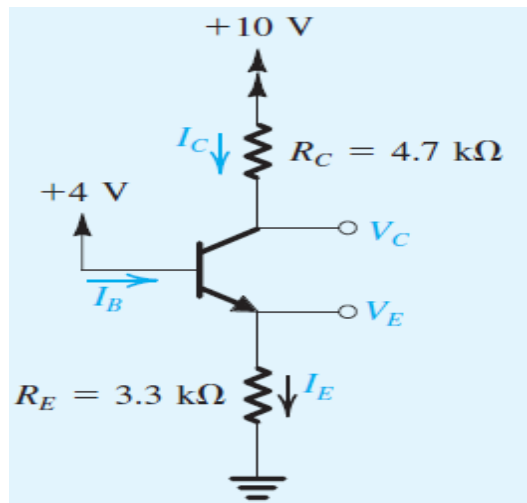


Assignment 2: Bipolar Junction Transistors

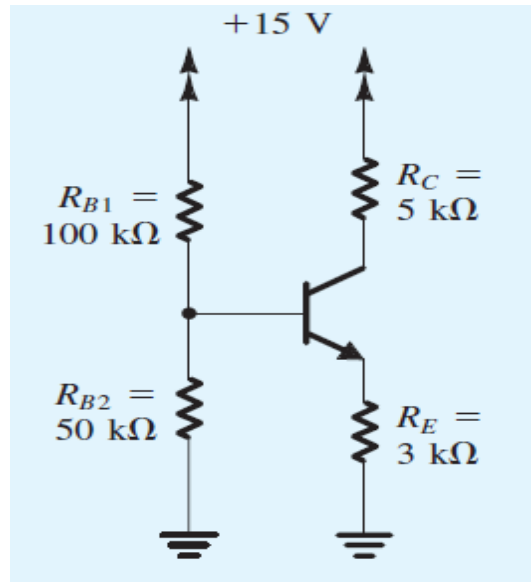
1. Explain the operation of NPN transistor in active mode with neat diagram?
2. What is early effect? How does it modify the V-I characteristics of a BJT?
3. Draw V-I Characteristics of a Transistor in CE Configurations and identify various region of operation?
4. The transistor in the circuit of figure shown has $\beta = 100$ and exhibits a v_{BE} of 0.7V at $i_C = 1\text{mA}$. Design the circuit so that a current of 2 mA flows through the collector and a voltage of +5V appears at the collector



5. Analyze the circuit shown in the figure to determine the voltages at all nodes and the currents through all branches. Assume $\beta = 100$.



6. Analyze the circuit shown in the figure to determine the voltages at all nodes and the currents through all branches. Assume $\beta = 100$.



7. Explain the applications of BJT as a switch and amplifier
8. Explain the various biasing methods in BJT
9. Draw the Small signal Low Frequency Equivalent Circuit of a CE Transistor Amplifier and derive the expression for Voltage gain, input and output impedance
(or) Explain in detail about BJT small signal model